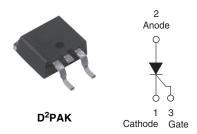


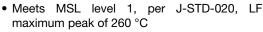
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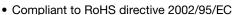
Surface Mountable Phase Control SCR, 10 A

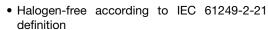


PRODUCT SUMMARY				
V _T at 6.5 A	< 1.15 V			
I _{TSM}	140 A			
V_{RRM}	800 V			

FEATURES







• Designed and qualified for industrial level





ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-10TTS08SPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
NEMA FR-4 or G-10 glass fabric-based epoxy with 4 oz. (140 μm) copper	2.5	3.5				
Aluminum IMS, R _{thCA} = 15 °C/W	6.3	9.5	А			
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	14.0	18.5				

Note

• $T_A = 55 \,^{\circ}\text{C}$, $T_J = 125 \,^{\circ}\text{C}$, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	6.5	۸			
I _{RMS}		10	Α			
V _{RRM} /V _{DRM}		800	V			
I _{TSM}		140	Α			
V _T	6.5 A, T _J = 25 °C	1.15	V			
dV/dt		150	V/µs			
dl/dt		100	A/µs			
T _J	Range	- 40 to 125	°C			

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA				
VS-10TTS08SPbF	800	800	1.0				

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Surface Mountable Phase Control SCR, 10 A



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Revision: 08-Jun-10

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	T _C = 112 °C, 180° conduc	tion half aine ways	6.5	•	
Maximum RMS on-state current	I _{T(RMS)}	1 _C = 112 C, 180 Conduc	tion hall sine wave	10		
Maximum peak, one-cycle,	1	10 ms sine pulse, rated V _F	RRM applied, T _J = 125 °C	120	Α	
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no volta	ge reapplied, T _J = 125 °C	140		
Marinarya 124 for fraing	l ² t	10 ms sine pulse, rated V _F	_{RRM} applied, T _J = 125 °C	72	A ² s	
Maximum I ² t for fusing	1-1	10 ms sine pulse, no voltage reapplied, T _J = 125 °C		100	A ^z S	
Maximum $I^2\sqrt{t}$ for fusing	I ² √t	t = 0.1 ms to 10 ms, no vo	Itage reapplied, T _J = 125 °C	1000	A²√s	
Maximum on-state voltage drop	V_{TM}	6.5 A, T _J = 25 °C		1.15	V	
On-state slope resistance	r _t	T 105.00		17.3	mΩ	
Threshold voltage	V _{T(TO)}	T _J = 125 °C		0.85	V	
Maximum various and divest leakers arranged	1 //	T _J = 25 °C	V Detect V A	0.05		
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	V _R = Rated V _{RRM} /V _{DRM}	1.0	A	
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I _T = 1 A		30	mA	
Maximum latching current	ΙL	Anode supply = 6 V, resistive load		50		
Maximum rate of rise of off-state voltage	dV/dt	T _J = 25 °C		150	V/µs	
Maximum rate of rise of turned-on current	dl/dt			100	A/μs	

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak gate power	P _{GM}		8.0 W			
Maximum average gate power	P _{G(AV)}		2.0	VV		
Maximum peak positive gate current	+I _{GM}		1.5	Α		
Maximum peak negative gate voltage	-V _{GM}		10	V		
	I _{GT}	Anode supply = 6 V, resistive load, T _J = - 65 °C	20	mA		
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, T _J = 25 °C	15			
		Anode supply = 6 V, resistive load, T _J = 125 °C	10			
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2			
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V		
voltage to trigger		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V		
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V Poted volve	0.2			
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	0.1	mA		

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8			
Typical reverse recovery time	t _{rr}	T _J = 125 °C	3	μs		
Typical turn-off time	t _q	1J = 125 G	100			

Surface Mountable Phase Control SCR, 10 A

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THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C		
Soldering temperature	Ts	For 10 s (1.6 mm from case)	240			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.5	°C/W		
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Marking device		Case style D ² PAK (SMD-220)	10TTS	08S		

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

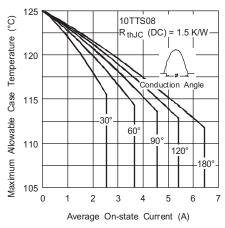


Fig. 1 - Current Rating Characteristics

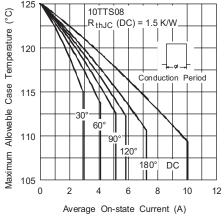


Fig. 2 - Current Rating Characteristics

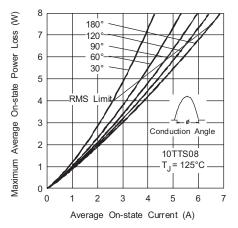


Fig. 3 - On-State Power Loss Characteristics

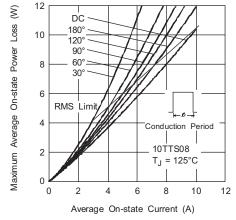


Fig. 4 - On-State Power Loss Characteristics

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Surface Mountable Phase Control SCR, 10 A



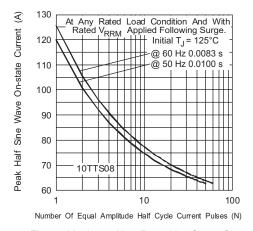


Fig. 5 - Maximum Non-Repetitive Surge Current

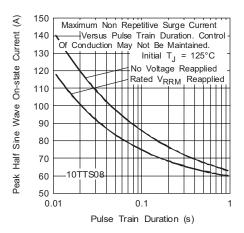


Fig. 6 - Maximum Non-Repetitive Surge Current

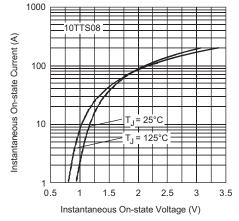


Fig. 7 - On-State Voltage Drop Characteristics

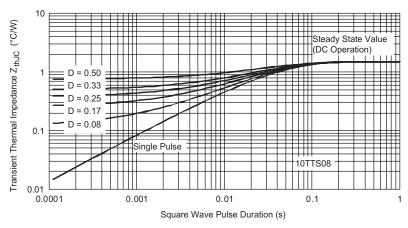


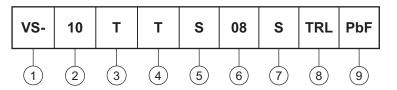
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Surface Mountable Phase Control SCR, 10 A Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 HPP product suffix
- 2 Current rating, RMS value
- Gircuit configuration:

 T = Single thyristor
- 4 Package:
 - T = TO-220AC
- 5 Type of silicon:
 - S = Converter grade
- 6 Voltage code x 100 = V_{RRM}
- 7 S = TO-220 D^2 PAK (SMD-220) version
- 8 Tape and reel option:
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 PbF = Lead (Pb)-free

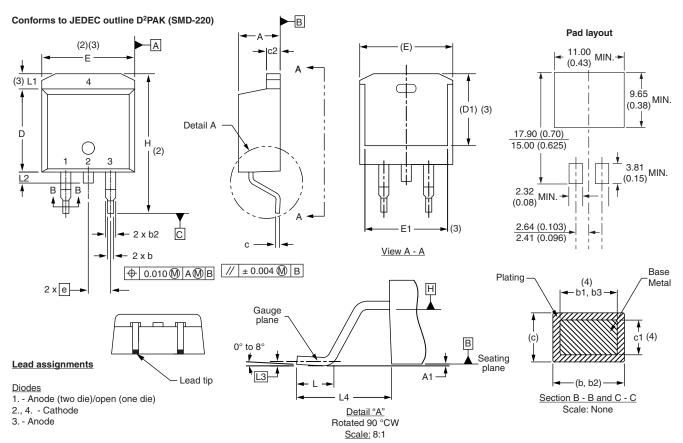
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95046			
Part marking information	www.vishay.com/doc?95054			
Packaging information	www.vishay.com/doc?95032			



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL MILLIMETERS		ETERS	INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	1	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB





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